# imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

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# Contact us

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# 2SB0792

#### Silicon PNP epitaxial planar type

For high breakdown voltage low-noise amplification

#### Features

- $\bullet$  High collector-emitter voltage (Base open)  $V_{CEO}$
- Low noise voltage NV
- Mini type package, allowing downsizing of the equipment and automatic insertion through the tape packing.

#### Package

- Code
- Mini3-G1

  Pin Name
  - 1. Base
  - 2. Emitter

Marking Symbol: I

3. Collector

<b>0</b> "				
Parameter	Symbol	Rating	Unit	
Collector-base voltage (Emitter open)	V <sub>CBO</sub>	-150	V	
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	-150	V	
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	-5	V	
Collector current	I <sub>C</sub>	-50	mA	
Peak collector current	I <sub>CP</sub>	-100	mA	
Collector power dissipation	P <sub>C</sub>	200	mW	
Junction temperature	Tj	150	°C	
Storage temperature	T <sub>stg</sub>	-55 to +150	°C	

#### Absolute Maximum Ratings $T_a = 25^{\circ}C$

## Electrical Characteristics $T_a = 25^{\circ}C \pm 3^{\circ}C$

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Collector-emitter voltage (Base open)	V <sub>CEO</sub>	$I_{\rm C} = -100 \ \mu \text{A}, I_{\rm B} = 0$	-150	5		V
Emitter-base voltage (Collector open)	V <sub>EBO</sub>	$I_{\rm E} = -10 \mu {\rm A}, I_{\rm C} = 0$	-5			V
Collector-base cutoff current (Emitter open)	I <sub>CBO</sub>	$V_{CB} = -100 \text{ V}, I_E = 0$	,X		-1	μΑ
Forward current transfer ratio *	$h_{\rm FE}$	$V_{CE} = -5 \text{ V}, I_C = -10 \text{ mA}$	130		450	
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	$I_{\rm C} = -30 \text{ mA}, I_{\rm B} = -3 \text{ mA}$			-1	V
Transition frequency	$\mathbf{f}_{\mathrm{T}}$	$V_{CB} = -10 \text{ V}, I_E = 10 \text{ mA}, f = 200 \text{ MHz}$		200		MHz
Collector output capacitance (Common base, input open circuited)	C <sub>ob</sub>	$V_{CB} = -10$ V, $I_E = 0$ , $f = 1$ MHz		4		pF
Noise voltage	NV	$V_{CB} = -10 \text{ V}, I_C = -1 \text{ mA}, G_V = 80 \text{ dB},$ $R_g = 100 \text{ k}\Omega, \text{ Function} = \text{FLAT}$		150		mV

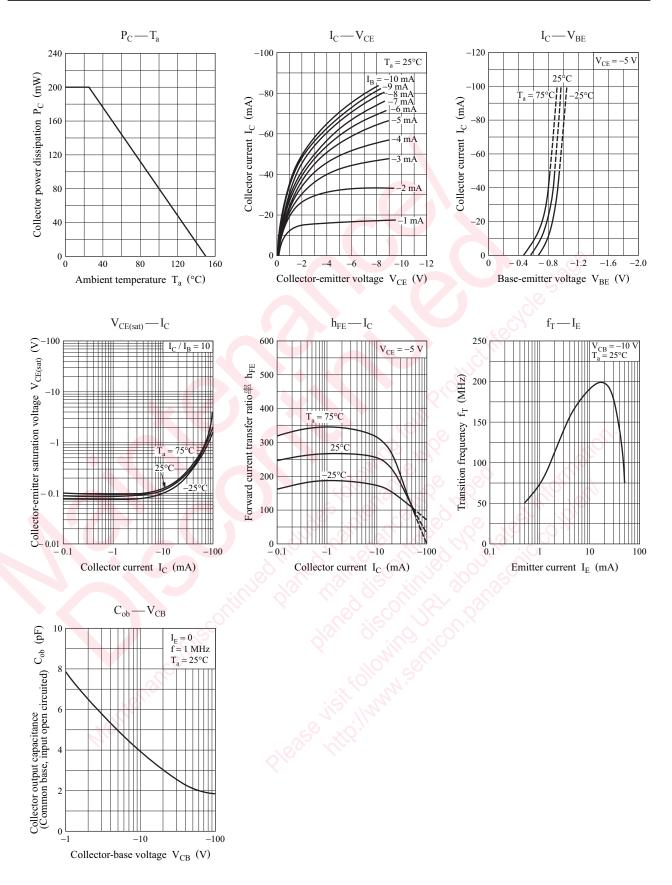
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. \*: Rank classification

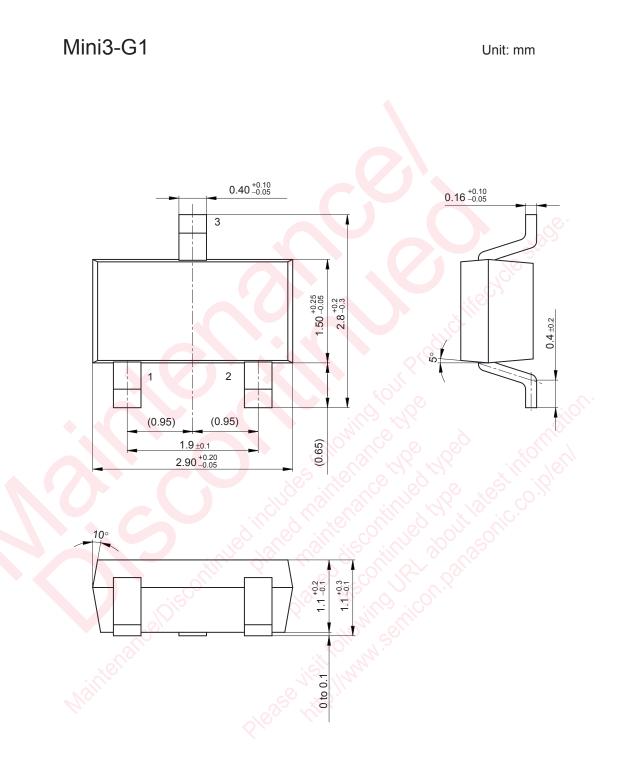
Rank	R	S	Т
$h_{\rm FE}$	130 to 220	185 to 330	260 to 450
Merking symbol	IR	IS	IT

#### 2SB0792

### **Panasonic**



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